LNA4401L

GaAlAs Infrared Light Emitting Diode

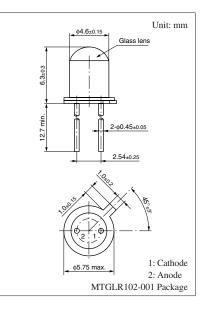
For optical control systems

Features

- High-power output, high-efficiency: $P_0 = 10 \text{ mW} \text{ (typ.)}$
- Fast response and high-speed modulation capability: $f_c = 20 \text{ MHz} \text{ (typ.)}$
- TO-18 standard type package

Absolute Maximum Hatings $T_a = 25$ C					
Symbol	Rating	Unit			
V _R	3	V			
$I_{\rm F}$	100	mA			
I_{FP}	1	А			
P _D	190	mW			
T _{opr}	-25 to +85	°C			
T _{stg}	-30 to +100	°C			
	Symbol V _R I _F P _D T _{opr}	$\begin{tabular}{ c c c c } \hline Symbol & Rating \\ \hline V_R & 3 \\ \hline I_F & 100 \\ \hline I_{FP} & 1 \\ \hline P_D & 190 \\ \hline T_{opr} & -25 \text{ to } +85 \\ \hline \end{tabular}$			

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Note) *: f = 100 Hz, Duty Cycle = 0.1%

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _F	$I_F = 100 \text{ mA}$		1.6	1.9	V
Reverse current	I _R	$V_R = 3 V$			10	μΑ
Radiant power	Po	I _F = 50 mA	6	10		mW
Peak emission wavelength	$\lambda_{\rm P}$	$I_F = 50 \text{ mA}$		860		nm
Spectral half band width	Δλ	I _F = 50 mA		40		nm
Half-power angle	θ	The angle when the radiant power is halved		6		0
Cutoff frequency *	f _C	$I_{FP} = 50 \text{ mA} + 10 \text{ mA}[p-p]$		20		MHz

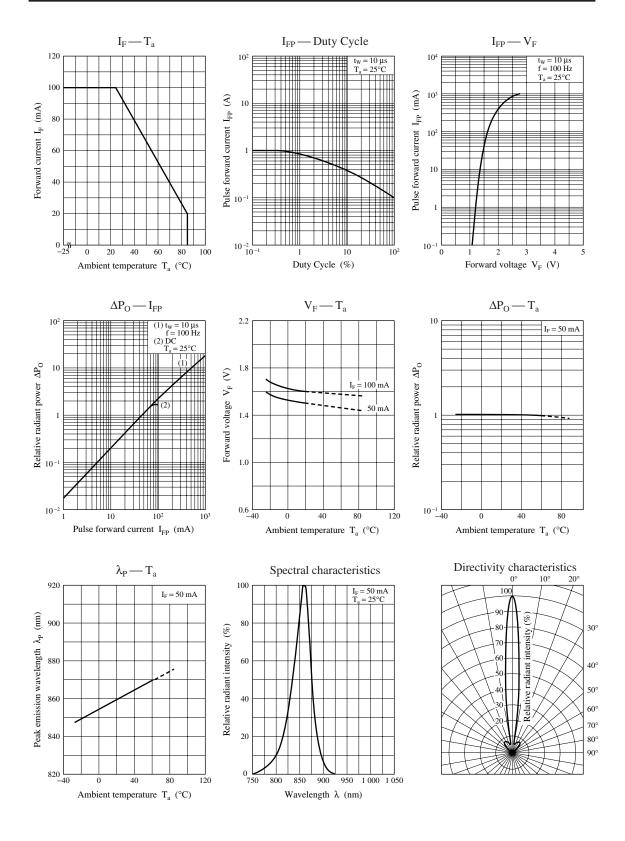
Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes. 2. *: Modulation total power output 3 dB frequency to fall from 1 MHz.

Cutoff frequency:

$$f_C: 10 \times \log \frac{P_O \text{ at } f = f_C}{P_O \text{ at } f = 1 \text{ MHz}} = -3$$

Panasonic



▲ Caution for Safety

⚠ DANGER

This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded form general industrial waste or household garbage.

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